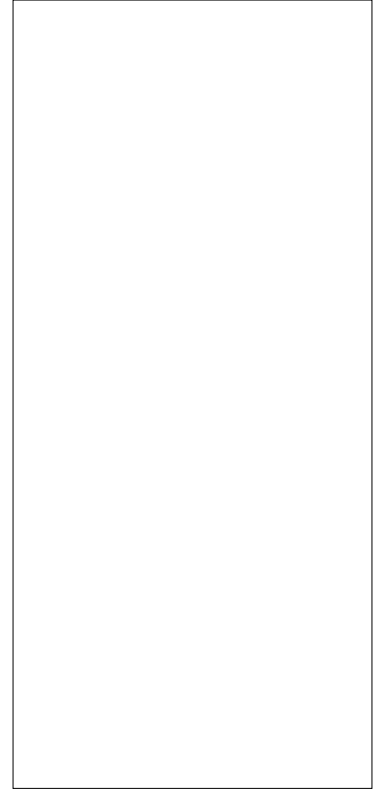




JCT820A



Peak gate current ($t_p=20 \text{ s}$, $T_j=125 \text{ }^\circ\text{C}$)	I_{GM}	5	A
Average gate power dissipation ($T_j=125 \text{ }^\circ\text{C}$)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	20	W
Peak pulse voltage ($T_j=25 \text{ }^\circ\text{C}$; non-repetitive,off-state;FIG.7)	V_{pp}	0.5	kV

ELECTRICAL CHARACTERISTICS (unless otherwise specified)

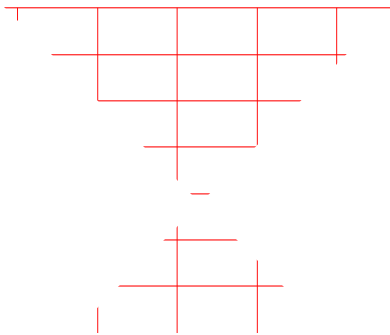
Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
I_{GT}	$V_D=12V$ $R_D=33\Omega$	-	-	15	mA
V_{GT}		-	-	1	V

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Q



Fig. 1: Maximum power dissipation versus
on-state current



PACKAGE MECHANICAL DATA

